



Features:

- Low Cost
- Surface Mount
- Aluminum Nitride Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Description

The RFP-250250N4AAXX is high performance Aluminum Nitride (AIN) surface mount attenuator intended as a lower cost alternative to Beryllium Oxide (BeO). The attenuator is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for inter-stage matching, directional couplers, and for use in isolators.

General Specifications

Resistive Element Thick film

Substrate Aluminum Nitride Ceramic

Terminal Finish Matte Tin over Sulfamate Nickel

Operating Temperature -55 to +125°C (see chart)

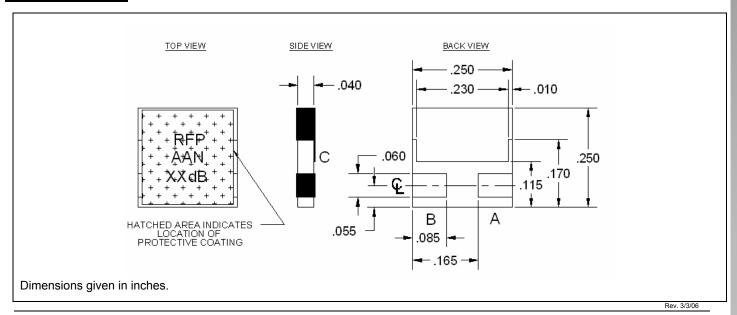
Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Attenuation Value:1-6, 9, 10dBPower:10 WattsFrequency Range:DC - 2.0 GHzV.S.W.R.:<1.25:1</th>

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Outline Drawing







Available on Tape and Reel For Pick and Place Manufacturing.

USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 Europe: +44 2392-232392





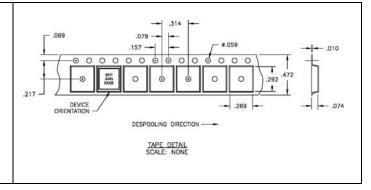
Specifications:

PART NUMBER	ATTENUATION(dB)	TOL. (±dB)	POWER (WATTS)	VSWR	FREQ (GHZ)
RFP-250250N4AA1	1	0.2	10	1.25:1	2.0
RFP-250250N4AA2	2	0.3	10	1.25:1	2.0
RFP-250250N4AA3	3	0.3	10	1.25:1	2.0
RFP-250250N4AA4	4	0.3	10	1.25:1	2.0
RFP-250250N4AA5	5	0.3	10	1.25:1	2.0
RFP-250250N4AA6	6	0.4	10	1.25:1	2.0
RFP-250250N4AA9	9	0.6	10	1.25:1	2.0
RFP-250250N4AA10	10	0.7	10	1.25:1	2.0

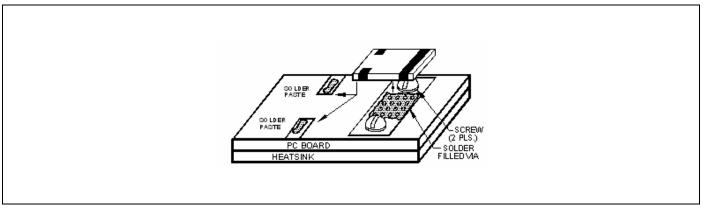
Power De-rating:

100 75 0 25 50 75 100 125 150 PCB TEMPERATURE - °C

Tape & Reel:



Mounting Footprint and Procedure:



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